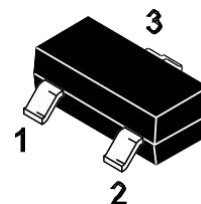


Features

- Low $R_{DS(ON)}$
- Surface Mount Package
- ESD protected(HBM) up to 2KV
- $V_{DS} = 30V, I_D = 0.5A$
 $R_{DS(on)} < 3\Omega @ V_{GS} = 10V$

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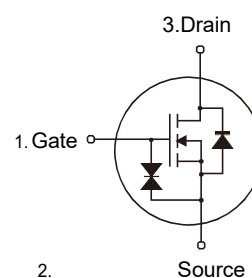
1. Gate 2. Source 3. Drain

Marking Code: 3018K

Applications

- Switching Application

Schematic Diagram



Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	0.5	A
Maximum Power Dissipation	P_D	0.35	W
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

Thermal Characteristics

Thermal Resistance, Junction-to-Ambient ^{Note1}	$R_{\theta JA}$	357	°C/W
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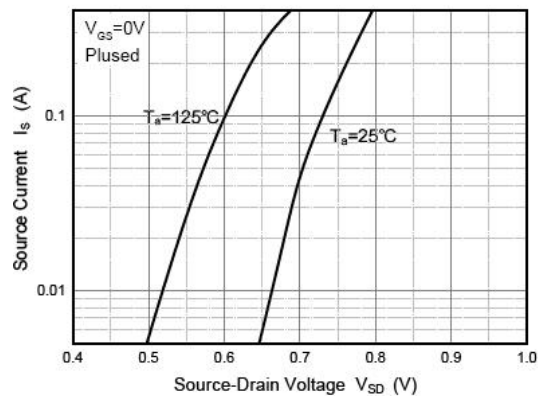
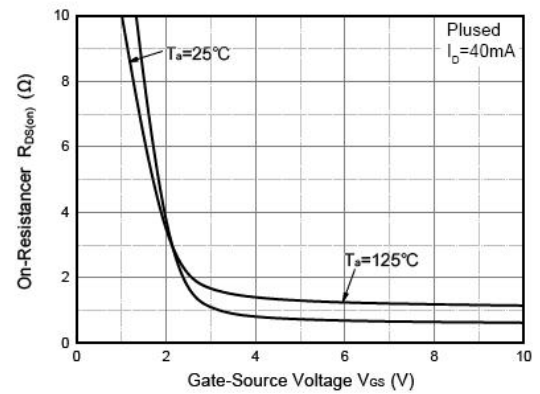
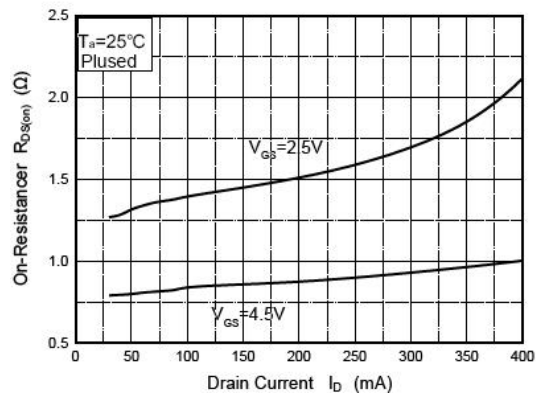
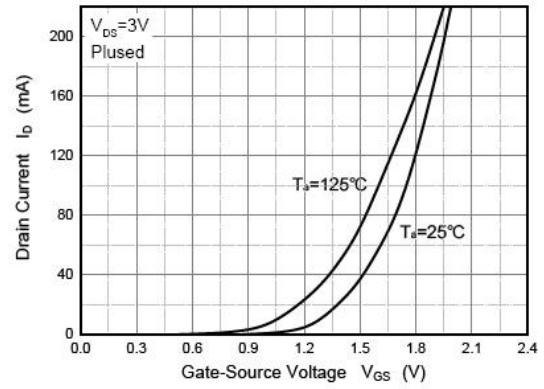
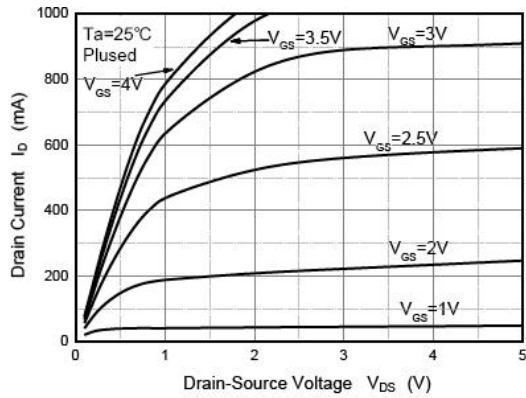
Electrical Characteristics

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	30	--	--	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	--	--	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	--	--	±10	μA
Gate Threshold Voltage ^{Note2}	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.8	--	2.5	V
Drain-Source On-Resistance ^{Note2}	R _{DS(on)}	V _{GS} =10V, I _D =0.3A	--	2	3	Ω
		V _{GS} =4.5V, I _D =0.2A	--	2.5	4	Ω
Forward Transconductance ^{Note2}	g _{FS}	V _{DS} =3V, I _D =10mA	20	--	--	mS
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =5V, V _{GS} =0V, f=1MHz	--	13	--	pF
Output Capacitance	C _{oss}		--	9	--	pF
Reverse Transfer Capacitance	C _{rss}		--	4	--	pF
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}	V _{DD} =5V, R _L =500Ω, I _D =10mA V _{GS} =5V, R _{GEN} =10Ω	--	13	--	nS
Turn-on Rise Time	t _r		--	35	--	nS
Turn-off Delay Time	t _{d(off)}		--	80	--	nS
Turn-off Fall Time	t _f		--	80	--	nS
Source-Drain Diode Characteristics						
Diode Forward Voltage ^{Note2}	V _{SD}	V _{GS} =0V, I _S =0.5A	--	--	1.2	V
Diode Forward Current ^{Note1}	I _S		--	--	0.5	A

Note: 1. Surface Mounted on FR4 Board, $t \leq 10$ sec.
2. Pulse Test: Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

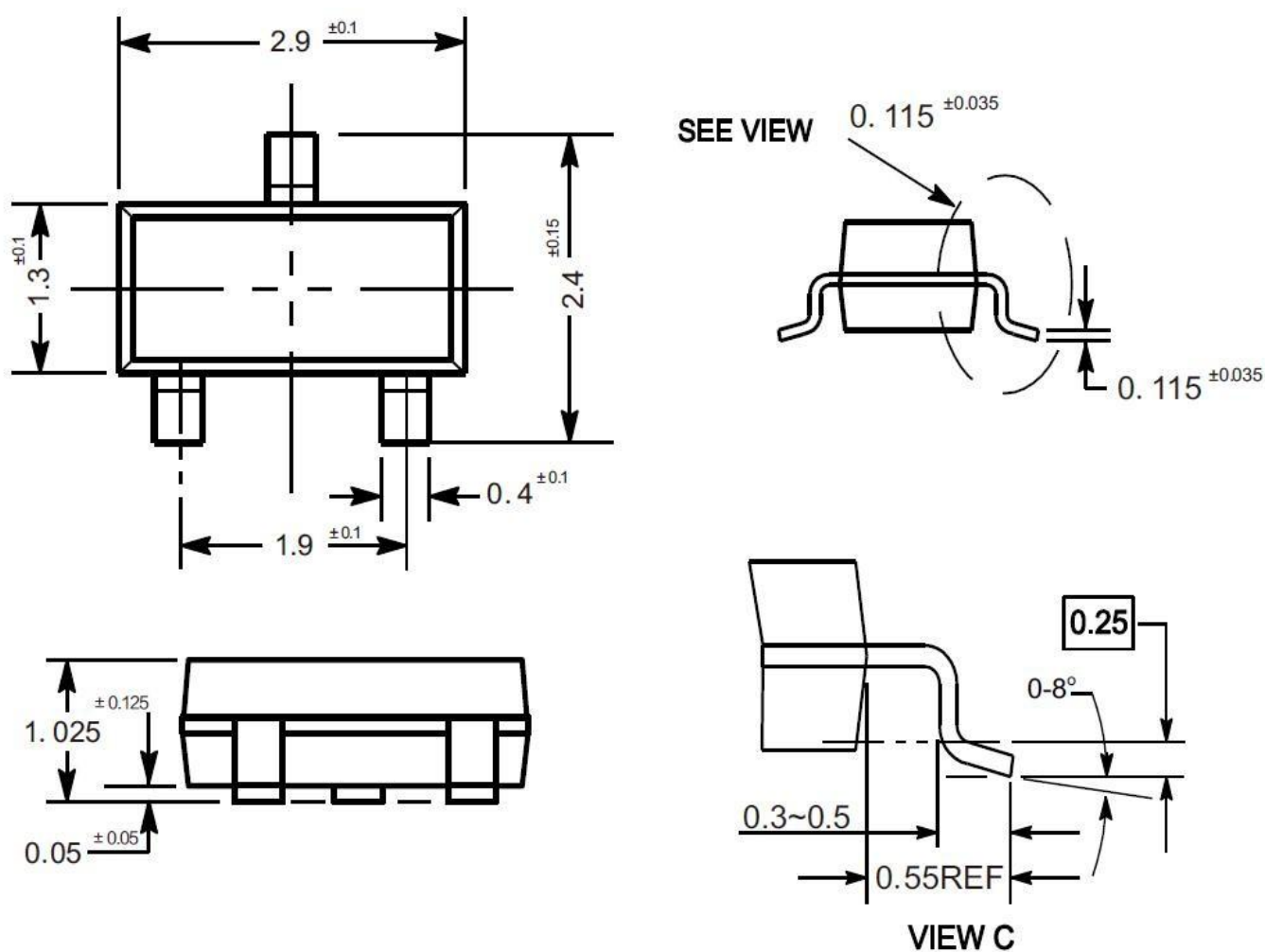
Typical Characteristic Curves



Package Outline

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Dimensions in mm

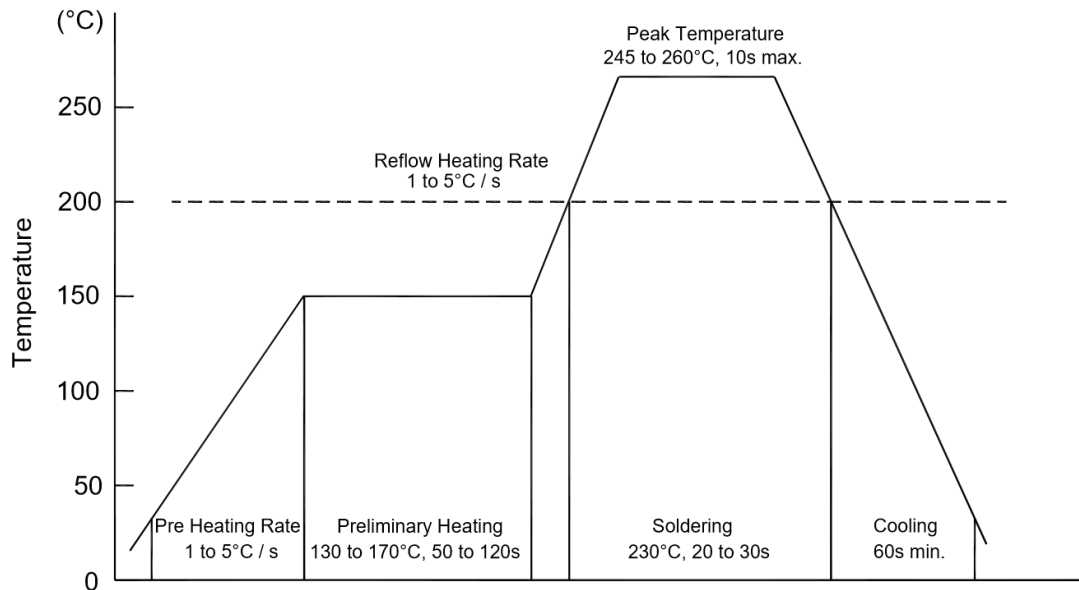


Ordering Information

Device	Package	Shipping
TN3018NSA	SOT-23	3,000PCS/Reel&7inches

Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

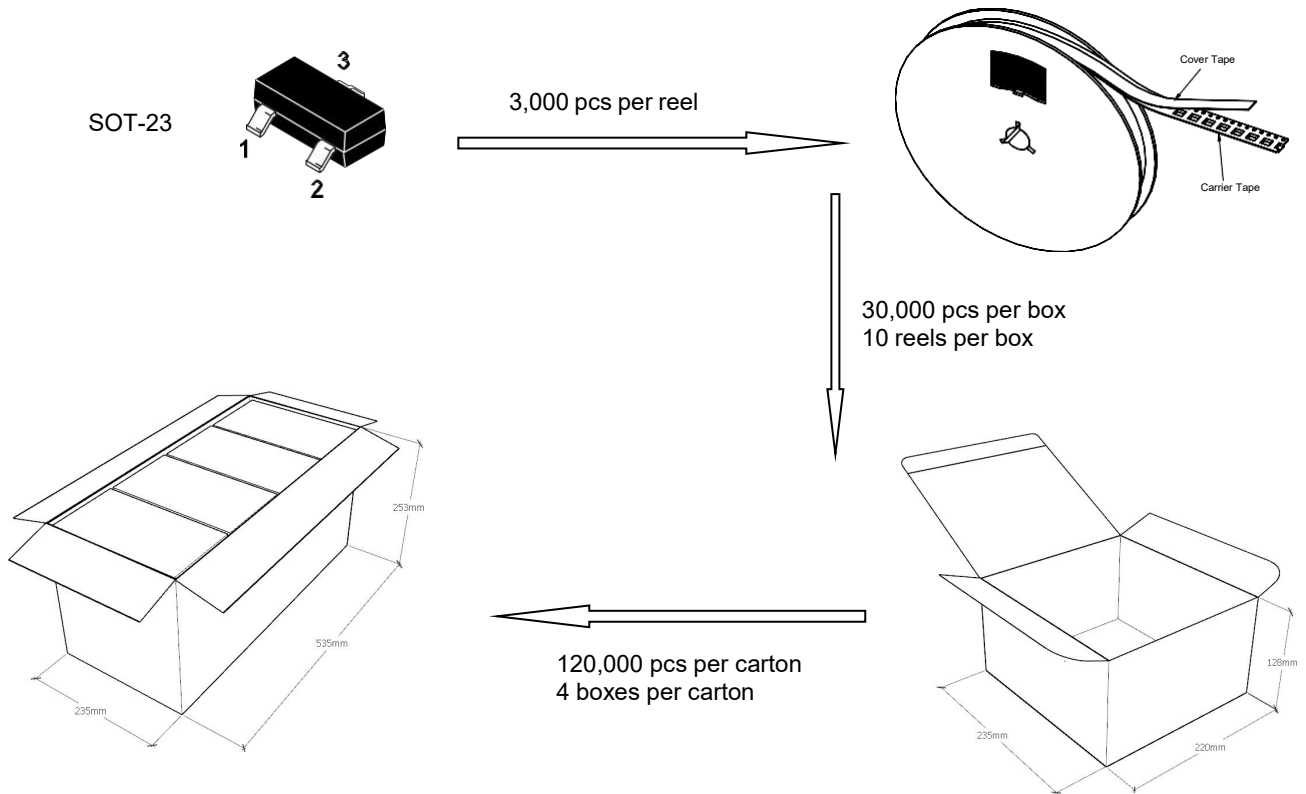
- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

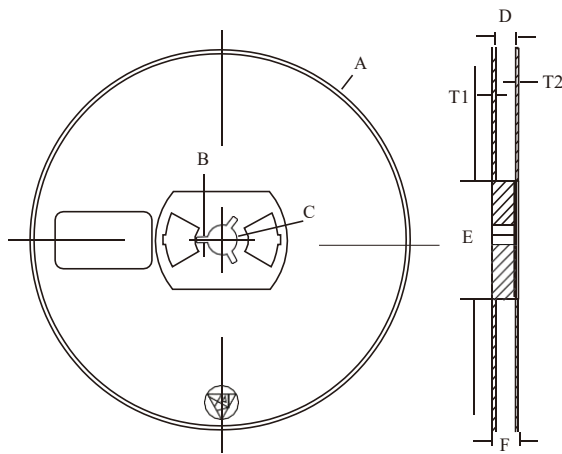
- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

Package Specifications

- The method of packaging



◆ Embossed tape and reel data



Reel (7")

Symbol	Value (unit: mm)
A	$\varnothing 177.8 \pm 1$
B	2.7 ± 0.2
C	$\varnothing 13.5 \pm 0.2$
E	$\varnothing 54.5 \pm 0.2$
F	12.3 ± 0.3
D	$9.6 \pm 2 / -0.3$
T1	1.0 ± 0.2
T2	1.2 ± 0.2

